

Edgardo Saucedo

List of Publications by Year in descending order

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Version: 2024-02-01

240
papers

8,112
citations

43973

48
h-index

62479

80
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243
all docs

243
docs citations

243
times ranked

4742
citing authors

#	ARTICLE	IF	CITATIONS
1	Atomic layer deposition of vanadium oxide films for crystalline silicon solar cells. <i>Materials Advances</i> , 2022, 3, 337-345.	2.6	20
2	Substrate temperature optimization of pulsed-laser-deposited and in-situ Zn-supplemented-CZTS films and their integration into photovoltaic devices. <i>Journal of Alloys and Compounds</i> , 2022, 893, 162292.	2.8	5
3	Numerical Investigation of Interface Passivation Strategies for Sb ₂ Se ₃ /CdS Solar Cells. <i>Solar Rrl</i> , 2022, 6, 2100911.	3.1	2
4	Does Sb ₂ Se ₃ Admit Nonstoichiometric Conditions? How Modifying the Overall Se Content Affects the Structural, Optical, and Optoelectronic Properties of Sb ₂ Se ₃ Thin Films. <i>ACS Applied Materials & Interfaces</i> , 2022, 14, 11222-11234.	4.0	17
5	Life cycle assessment of different chalcogenide thin-film solar cells. <i>Applied Energy</i> , 2022, 313, 118888.	5.1	13
6	Effect of post annealing thermal heating on Cu ₂ ZnSnS ₄ solar cells processed by sputtering technique. <i>Solar Energy</i> , 2022, 237, 196-202.	2.9	17
7	Towards Low Cost and Sustainable Thin Film Thermoelectric Devices Based on Quaternary Chalcogenides. <i>Advanced Functional Materials</i> , 2022, 32, .	7.8	26
8	Kinetics and phase analysis of kesterite compounds: Influence of chalcogen availability in the reaction pathway. <i>Materialia</i> , 2022, 24, 101509.	1.3	2
9	Defect depth-profiling in kesterite absorber by means of chemical etching and surface analysis. <i>Applied Surface Science</i> , 2021, 540, 148342.	3.1	6
10	Rear interface engineering of kesterite Cu ₂ ZnSnSe ₄ solar cells by adding CuGaSe ₂ thin layers. <i>Progress in Photovoltaics: Research and Applications</i> , 2021, 29, 334-343.	4.4	11
11	Combinatorial and machine learning approaches for the analysis of Cu ₂ ZnGeSe ₄ : influence of the off-stoichiometry on defect formation and solar cell performance. <i>Journal of Materials Chemistry A</i> , 2021, 9, 10466-10476.	5.2	13
12	Emerging inorganic solar cell efficiency tables (version 2). <i>JPhys Energy</i> , 2021, 3, 032003.	2.3	40
13	Feasibility of a Full Chalcopyrite Tandem Solar Cell: A Quantitative Numerical Approach. <i>Solar Rrl</i> , 2021, 5, 2100202.	3.1	4
14	Evaluation of hetero and back contact junctions of CZTSe: Ge bilayers solar cells with Modulus Spectroscopy. , 2021, , .		0
15	Estimation of front and back junctions of CZTSe:Ge solar cells by combined modulus and impedance spectroscopy. <i>Journal Physics D: Applied Physics</i> , 2021, 54, 335501.	1.3	5
16	Bromine etching of kesterite thin films: perspectives in depth defect profiling and device performance improvement. , 2021, , .		1
17	Insights on the Thermal Stability of the Sb ₂ Se ₃ Quasi-1D Photovoltaic Technology. <i>Solar Rrl</i> , 2021, 5, 2100517.	3.1	2
18	Insights on the limiting factors of Cu ₂ ZnGeSe ₄ based solar cells. <i>Solar Energy Materials and Solar Cells</i> , 2021, 227, 111106.	3.0	6

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19	Hole Transport Layer based on atomic layer deposited V ₂ O ₅ films: Paving the road to semi-transparent CZTSe solar cells. <i>Solar Energy</i> , 2021, 226, 64-71.	2.9	3
20	High efficiency Cu ₂ ZnSnS ₄ solar cells over FTO substrates and their CZTS/CdS interface passivation via thermal evaporation of Al ₂ O ₃ . <i>Journal of Materials Chemistry C</i> , 2021, 9, 5356-5361.	2.7	10
21	Insights into interface and bulk defects in a high efficiency kesterite-based device. <i>Energy and Environmental Science</i> , 2021, 14, 507-523.	15.6	48
22	Structural and vibrational properties of β - and γ -SnS polymorphs for photovoltaic applications. <i>Acta Materialia</i> , 2020, 183, 1-10.	3.8	43
23	In-situ tuning of the zinc content of pulsed-laser-deposited CZTS films and its effect on the photoconversion efficiency of p-CZTS/n-Si heterojunction photovoltaic devices. <i>Applied Surface Science</i> , 2020, 507, 145003.	3.1	31
24	Continuous-wave laser annealing of metallic layers for CuInSe ₂ solar cell applications: effect of preheating treatment on grain growth. <i>RSC Advances</i> , 2020, 10, 584-594.	1.7	2
25	On the Germanium Incorporation in Cu ₂ ZnSnSe ₄ Kesterite Solar Cells Boosting Their Efficiency. <i>ACS Applied Energy Materials</i> , 2020, 3, 558-564.	2.5	11
26	UV-Selective Optically Transparent Zn(O,S)-Based Solar Cells. <i>Solar Rrl</i> , 2020, 4, 2070112.	3.1	0
27	Rear Band gap Grading Strategies on Sn-Ge-Alloyed Kesterite Solar Cells. <i>ACS Applied Energy Materials</i> , 2020, 3, 10362-10375.	2.5	29
28	Investigation on limiting factors affecting Cu ₂ ZnGeSe ₄ efficiency: Effect of annealing conditions and surface treatment. <i>Solar Energy Materials and Solar Cells</i> , 2020, 216, 110701.	3.0	17
29	Partial substitution of the CdS buffer layer with interplay of fullerenes in kesterite solar cells. <i>Journal of Materials Chemistry C</i> , 2020, 8, 12533-12542.	2.7	13
30	UV-Selective Optically Transparent Zn(O,S)-Based Solar Cells. <i>Solar Rrl</i> , 2020, 4, 2000470.	3.1	12
31	Cu-Sn-S system: Vibrational properties and coexistence of the Cu ₂ SnS ₃ , Cu ₃ SnS ₄ and Cu ₄ SnS ₄ compounds. <i>Scripta Materialia</i> , 2020, 186, 180-184.	2.6	15
32	Efficient Sb ₂ Se ₃ /CdS planar heterojunction solar cells in substrate configuration with (hk0) oriented Sb ₂ Se ₃ thin films. <i>Solar Energy Materials and Solar Cells</i> , 2020, 215, 110603.	3.0	28
33	CdS/ZnS Bilayer Thin Films Used As Buffer Layer in 10%-Efficient Cu ₂ ZnSnSe ₄ Solar Cells. <i>ACS Applied Energy Materials</i> , 2020, 3, 6815-6823.	2.5	21
34	Uncovering details behind the formation mechanisms of Cu ₂ ZnGeSe ₄ photovoltaic absorbers. <i>Journal of Materials Chemistry C</i> , 2020, 8, 4003-4011.	2.7	13
35	Transition-Metal Oxides for Kesterite Solar Cells Developed on Transparent Substrates. <i>ACS Applied Materials & Interfaces</i> , 2020, 12, 33656-33669.	4.0	29
36	Efficient Se-Rich Sb ₂ Se ₃ /CdS Planar Heterojunction Solar Cells by Sequential Processing: Control and Influence of Se Content. <i>Solar Rrl</i> , 2020, 4, 2070075.	3.1	5

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37	CZTS solar cells and the possibility of increasing VOC using evaporated Al ₂ O ₃ at the CZTS/CdS interface. <i>Solar Energy</i> , 2020, 198, 696-703.	2.9	28
38	Sputtered ZnSnO Buffer Layers for Kesterite Solar Cells. <i>ACS Applied Energy Materials</i> , 2020, 3, 1883-1891.	2.5	23
39	Efficient Se-Rich Sb ₂ Se ₃ /CdS Planar Heterojunction Solar Cells by Sequential Processing: Control and Influence of Se Content. <i>Solar Rrl</i> , 2020, 4, 2000141.	3.1	23
40	Over 10% Efficient Wide Bandgap CIGSe Solar Cells on Transparent Substrate with Na Predeposition Treatment. <i>Solar Rrl</i> , 2020, 4, 2000284.	3.1	8
41	Influence of co-electrodeposition parameters in the synthesis of kesterite thin films for photovoltaic. <i>Journal of Alloys and Compounds</i> , 2020, 839, 155679.	2.8	10
42	Is It Possible To Develop Complex Se Graded Band Gap Profiles in Kesterite-Based Solar Cells?. <i>ACS Applied Materials & Interfaces</i> , 2019, 11, 32945-32956.	4.0	42
43	Multiwavelength excitation Raman scattering study of Sb ₂ Se ₃ compound: fundamental vibrational properties and secondary phases detection. <i>2D Materials</i> , 2019, 6, 045054.	2.0	69
44	Engineering of effective back-contact barrier of CZTSe: Nanoscale Ge solar cells – MoSe ₂ defects implication. <i>Solar Energy</i> , 2019, 194, 114-120.	2.9	18
45	Study and optimization of alternative MBE-deposited metallic precursors for highly efficient kesterite CZTSe:Ge solar cells. <i>Progress in Photovoltaics: Research and Applications</i> , 2019, 27, 779-788.	4.4	12
46	Kesterite: New Progress Toward Earth-Abundant Thin-Film Photovoltaic. , 2019, , 93-120.		3
47	CuZnInSe ₃ -based solar cells: Impact of copper concentration on vibrational and structural properties and device performance. <i>Progress in Photovoltaics: Research and Applications</i> , 2019, 27, 716-723.	4.4	7
48	Physical routes for the synthesis of kesterite. <i>JPhys Energy</i> , 2019, 1, 042003.	2.3	34
49	Emerging inorganic solar cell efficiency tables (Version 1). <i>JPhys Energy</i> , 2019, 1, 032001.	2.3	54
50	Defect characterisation in Cu ₂ ZnSnSe ₄ kesterites via resonance Raman spectroscopy and the impact on optoelectronic solar cell properties. <i>Journal of Materials Chemistry A</i> , 2019, 7, 13293-13304.	5.2	63
51	Evaluation of AA-CVD deposited phase pure polymorphs of SnS for thin films solar cells. <i>RSC Advances</i> , 2019, 9, 14899-14909.	1.7	42
52	Ge doped Cu ₂ ZnSnS ₄ : An investigation on absorber recrystallization and opto-electronic properties of solar cell. <i>Solar Energy Materials and Solar Cells</i> , 2019, 198, 44-52.	3.0	20
53	Progress and Perspectives of Thin Film Kesterite Photovoltaic Technology: A Critical Review. <i>Advanced Materials</i> , 2019, 31, e1806692.	11.1	333
54	Impact of Thin CuGa Layers Added at the Rear Interface of Cu ₂ ZnSnSe ₄ Solar Cells. , 2019, , .		0

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55	Multi-layered photocathodes based on Cu ₂ ZnSnSe ₄ absorber and MoS ₂ catalyst for the hydrogen evolution reaction. Journal of Materials Chemistry A, 2019, 7, 24320-24327.	5.2	8
56	Insights into the Formation Pathways of Cu ₂ ZnSnSe ₄ Using Rapid Thermal Processes. ACS Applied Energy Materials, 2018, 1, 1981-1989.	2.5	16
57	Improved quantum efficiency models of CZTSe: Ge nanolayer solar cells with a linear electric field. Nanoscale, 2018, 10, 2990-2997.	2.8	14
58	Turning Earth Abundant Kesterite-Based Solar Cells Into Efficient Protected Water-Splitting Photocathodes. ACS Applied Materials & Interfaces, 2018, 10, 13425-13433.	4.0	31
59	Cu content dependence of Cu ₂ Zn(SnGe)Se ₄ solar cells prepared by using sequential thermal evaporation technique of Cu/Sn/Cu/Zn/Ge stacked layers. Journal of Materials Science: Materials in Electronics, 2018, 29, 15363-15368.	1.1	6
60	How small amounts of Ge modify the formation pathways and crystallization of kesterites. Energy and Environmental Science, 2018, 11, 582-593.	15.6	169
61	C ₂ TSe solar cells developed on polymer substrates: Effects of low-temperature processing. Progress in Photovoltaics: Research and Applications, 2018, 26, 55-68.	4.4	23
62	Optimization of ink-jet printed precursors for Cu ₂ ZnSn(S,Se) ₄ solar cells. Journal of Alloys and Compounds, 2018, 735, 2462-2470.	2.8	16
63	Double band gap gradients in sequentially processed photovoltaic absorbers from the Cu(In,Ga)Se ₂ -ZnSe pseudobinary system. Progress in Photovoltaics: Research and Applications, 2018, 26, 135-144.	4.4	7
64	Enhanced Heterojunction Quality and Performance of Kesterite Solar Cells by Aluminum Hydroxide Nanolayers and Efficiency Limitation Revealed by Atomic-resolution Scanning Transmission Electron Microscopy. Solar Rrl, 2018, 3, 1800279.	3.1	6
65	Improved Back Contact Barrier of CZTSe solar cells by incorporating nanoscale Ge bi-layers. , 2018, , .		0
66	Improved Device Models of CZTSe: nanolayer Ge solar cells with Quantum Efficiency. , 2018, , .		2
67	Tailoring doping of efficient Sb ₂ Se ₃ solar cells in substrate configuration by low temperature post deposition selenization process. , 2018, , .		2
68	Doping Effects on Kesterites Other than Alkalis. , 2018, , .		2
69	An innovative alkali doping strategy for Cu₂ZnSnSe₄ through the CdS buffer layer. , 2018, , .		1
70	Revealing the beneficial effects of Ge doping on Cu₂ZnSnSe₄ thin film solar cells. Journal of Materials Chemistry A, 2018, 6, 11759-11772.	5.2	46
71	Pre-annealing of metal stack precursors and its beneficial effect on kesterite absorber properties and device performance. Solar Energy Materials and Solar Cells, 2018, 185, 226-232.	3.0	11
72	Thin film photovoltaic devices prepared with Cu ₃ BiS ₃ ternary compound. Materials Science in Semiconductor Processing, 2018, 87, 37-43.	1.9	9

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73	Cu ₂ ZnSnSe ₄ based solar cells combining co-electrodeposition and rapid thermal processing. Solar Energy, 2018, 173, 955-963.	2.9	13
74	Discrepancy between integral and local composition in off-stoichiometric Cu ₂ ZnSnSe ₄ kesterites: A pitfall for classification. Applied Physics Letters, 2017, 110, .	1.5	19
75	Cationic compositional optimization of CuIn(S _{1-y} Se _y) ₂ ultra-thin layers obtained by chemical bath deposition. Applied Surface Science, 2017, 404, 57-62.	3.1	4
76	Chemically and morphologically distinct grain boundaries in Ge-doped Cu ₂ ZnSnSe ₄ solar cells revealed with STEM-EELS. Materials and Design, 2017, 122, 102-109.	3.3	16
77	Processing pathways of Cu ₂ Zn(SnGe)Se ₄ based solar cells: The role of CdS buffer layer. Materials Science in Semiconductor Processing, 2017, 67, 14-19.	1.9	9
78	Cu ₂ ZnSnS ₄ thin film solar cells grown by fast thermal evaporation and thermal treatment. Solar Energy, 2017, 141, 236-241.	2.9	32
79	Chemistry and Dynamics of Ge in Kesterite: Toward Band-Gap-Graded Absorbers. Chemistry of Materials, 2017, 29, 9399-9406.	3.2	59
80	Bifacial Kesterite Solar Cells on FTO Substrates. ACS Sustainable Chemistry and Engineering, 2017, 5, 11516-11524.	3.2	45
81	Characterization of Cu ₂ SnS ₃ polymorphism and its impact on optoelectronic properties. Journal of Materials Chemistry A, 2017, 5, 23863-23871.	5.2	56
82	Valence and conduction band edges of selenide and sulfide-based kesterites—a study by x-ray based spectroscopy and ab initio theory. Semiconductor Science and Technology, 2017, 32, 104010.	1.0	1
83	Enhanced photoelectrochemical water splitting of hematite multilayer nanowire photoanodes by tuning the surface state via bottom-up interfacial engineering. Energy and Environmental Science, 2017, 10, 2124-2136.	15.6	185
84	Towards In-reduced photovoltaic absorbers: Evaluation of zinc-blende CuInSe ₂ -ZnSe solid solution. Solar Energy Materials and Solar Cells, 2017, 160, 26-33.	3.0	15
85	Towards understanding poor performances in spray-deposited Cu ₂ ZnSnS ₄ thin film solar cells. Solar Energy Materials and Solar Cells, 2017, 159, 151-158.	3.0	54
86	Raman scattering assessment of point defects in kesterite semiconductors: UV resonant Raman characterization for advanced photovoltaics. , 2017, , .		3
87	Optical modeling and optimizations of Cu ₂ ZnSnSe ₄ solar cells using the modified transfer matrix method. Optics Express, 2016, 24, A1201.	1.7	20
88	Special issue “Nanotechnology for next generation high efficiency photovoltaics: NEXTGEN NANOPV Spring International School & Workshop” Solar Energy Materials and Solar Cells, 2016, 158, 123-125.	3.0	0
89	Detrimental effect of Sn-rich secondary phases on Cu ₂ ZnSnSe ₄ based solar cells. Journal of Renewable and Sustainable Energy, 2016, 8, 033502.	0.8	6
90	Overcoming the Voc limitation of CZTSe solar cells. , 2016, , .		2

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91	Post-deposition annealing of Cu ₂ ZnSnSe ₄ /CdS based solar cells: Analysis of the absorber's surface defects. , 2016, , .		0
92	Advanced hybrid buffer layers for Cu ₂ ZnSnSe ₄ solar cells. , 2016, , .		1
93	Enhancing grain growth and boosting Voc in CZTSe absorber layers " Is Ge doping the answer?. , 2016, , .		1
94	Development of Cu ₂ SnS ₃ based solar cells by a sequential process. , 2016, , .		0
95	The Cu(In, Ga)Se ₂ -ZnSe system: Optimizing solid solutions for high V _{OC} photovoltaic devices. , 2016, , .		0
96	CdS bi-layers for optimized CdS/Cu ₂ ZnSnSe ₄ solar cells. , 2016, , .		0
97	8.2% pure selenide kesterite thin-film solar cells from large-area electrodeposited precursors. Progress in Photovoltaics: Research and Applications, 2016, 24, 38-51.	4.4	52
98	Selenization of Cu ₂ ZnSnS ₄ thin films obtained by pneumatic spray pyrolysis. Journal of Analytical and Applied Pyrolysis, 2016, 120, 45-51.	2.6	11
99	Vitreous enamel as sodium source for efficient kesterite solar cells on commercial ceramic tiles. Solar Energy Materials and Solar Cells, 2016, 154, 11-17.	3.0	10
100	<i>V_{oc}</i> Boosting and Grain Growth Enhancing Ge-Doping Strategy for Cu ₂ ZnSnSe ₄ Photovoltaic Absorbers. Journal of Physical Chemistry C, 2016, 120, 9661-9670.	1.5	69
101	Cu ₂ ZnSnSe ₄ -Based Solar Cells With Efficiency Exceeding 10% by Adding a Superficial Ge Nanolayer: The Interaction Between Ge and Na. IEEE Journal of Photovoltaics, 2016, 6, 754-759.	1.5	28
102	Influence of Amorphous Silicon Carbide Intermediate Layer in the Back-Contact Structure of Cu ₂ ZnSnSe ₄ Solar Cells. IEEE Journal of Photovoltaics, 2016, 6, 1327-1332.	1.5	8
103	Raman scattering analysis of the surface chemistry of kesterites: Impact of post-deposition annealing and Cu/Zn reordering on solar cell performance. Solar Energy Materials and Solar Cells, 2016, 157, 462-467.	3.0	71
104	Cu ₂ ZnSnSe ₄ solar cells with 10.6% efficiency through innovative absorber engineering with Ge superficial nanolayer. Progress in Photovoltaics: Research and Applications, 2016, 24, 1359-1367.	4.4	77
105	Bi-directional crystallization of Cu ₂ ZnSnSe ₄ assisted with back/front Ge nanolayers. , 2016, , .		1
106	Compositional Dependence of Chemical and Electrical Properties in Cu ₂ ZnSnS ₄ Thin Films. IEEE Journal of Photovoltaics, 2016, 6, 990-996.	1.5	10
107	The importance of back contact modification in Cu ₂ ZnSnSe ₄ solar cells: The role of a thin MoO ₂ layer. Nano Energy, 2016, 26, 708-721.	8.2	77
108	Temperature dependent electrical characterization of thin film Cu ₂ ZnSnSe ₄ solar cells. Journal Physics D: Applied Physics, 2016, 49, 085101.	1.3	21

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109	Ultra-thin CdS for highly performing chalcogenides thin film based solar cells. Solar Energy Materials and Solar Cells, 2016, 158, 138-146.	3.0	31
110	Alkali doping strategies for flexible and light-weight $\text{Cu}_{2-x}\text{ZnSnSe}_4$ solar cells. Journal of Materials Chemistry A, 2016, 4, 1895-1907.	5.2	88
111	Optical methodology for process monitoring of chalcopyrite photovoltaic technologies: Application to low cost $\text{Cu}(\text{In,Ga})(\text{S,Se})_2$ electrodeposition based processes. Solar Energy Materials and Solar Cells, 2016, 158, 168-183.	3.0	51
112	Optimization of CBD-CdS physical properties for solar cell applications considering a MIS structure. Materials and Design, 2016, 99, 254-261.	3.3	18
113	Optical and electrical properties of In-doped $\text{Cu}_2\text{ZnSnSe}_4$. Solar Energy Materials and Solar Cells, 2016, 151, 44-51.	3.0	19
114	Secondary phase and Cu substitutional defect dynamics in kesterite solar cells: Impact on optoelectronic properties. Solar Energy Materials and Solar Cells, 2016, 149, 304-309.	3.0	82
115	Impact of Na Dynamics at the $\text{Cu}_{2-x}\text{ZnSn}(\text{S,Se})_4/\text{CdS}$ Interface During Post Low Temperature Treatment of Absorbers. ACS Applied Materials & Interfaces, 2016, 8, 5017-5024.	4.0	72
116	Effect of rapid thermal annealing on the Mo back contact properties for $\text{Cu}_2\text{ZnSnSe}_4$ solar cells. Journal of Alloys and Compounds, 2016, 675, 158-162.	2.8	14
117	Towards high performance Cd-free CZTSe solar cells with a $\text{ZnS}(\text{O,OH})$ buffer layer: the influence of thiourea concentration on chemical bath deposition. Journal Physics D: Applied Physics, 2016, 49, 125602.	1.3	39
118	Role of S and Se atoms on the microstructural properties of kesterite $\text{Cu}_{2-x}\text{ZnSn}(\text{S}_{1-x}\text{Se}_x)_4$ thin film solar cells. Physical Chemistry Chemical Physics, 2016, 18, 8692-8700.	1.3	43
119	Resonant Raman scattering of $\text{ZnS}_x\text{Se}_{1-x}$ solid solutions: the role of S and Se electronic states. Physical Chemistry Chemical Physics, 2016, 18, 7632-7640.	1.3	43
120	Efficient bifacial $\text{Cu}_2\text{ZnSnSe}_4$ solar cells. , 2015, , .		3
121	High efficiency $\text{Cu}_2\text{ZnSnSe}_4$:In doped based solar cells. , 2015, , .		1
122	Assessment of Chemical and Electronic Surface Properties of the $\text{Cu}_2\text{ZnSn}(\text{S,Se})_4$ After Different Etching Procedures by Synchrotron-based Spectroscopies. Energy Procedia, 2015, 84, 8-16.	1.8	6
123	$\text{Cu}_2\text{ZnSnSe}_4$ based solar cells prepared at high temperatures on Si/SiO ₂ sodium-free substrate. , 2015, , .		0
124	Large Efficiency Improvement in $\text{Cu}_{2-x}\text{ZnSnSe}_4$ Solar Cells by Introducing a Superficial Ge Nanolayer. Advanced Energy Materials, 2015, 5, 1501070.	10.2	188
125	Temperature dependent electroreflectance study of $\text{Cu}_2\text{ZnSnSe}_4$ solar cells. Materials Science in Semiconductor Processing, 2015, 39, 251-254.	1.9	13
126	Investigation of selenization process of electrodeposited $\text{Cu}^{\text{II}}\text{Zn}^{\text{II}}\text{Sn}^{\text{II}}$ precursor for $\text{Cu}_2\text{ZnSnSe}_4$ thin-film solar cells. Thin Solid Films, 2015, 589, 165-172.	0.8	5

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127	Large performance improvement in Cu ₂ ZnSnSe ₄ based solar cells by surface engineering with a nanometric Ge layer. , 2015, , .		4
128	1D and 2D numerical simulations of Cu ₂ ZnSnSe ₄ solar cells. , 2015, , .		3
129	Chemical bath deposition route for the synthesis of ultra-thin CuIn(S,Se) ₂ based solar cells. Thin Solid Films, 2015, 582, 74-78.	0.8	6
130	Optimization of CdS buffer layer for high performance Cu ₂ ZnSnSe ₄ solar cells and the effects of light soaking: elimination of crossover and red kink. Progress in Photovoltaics: Research and Applications, 2015, 23, 1660-1667.	4.4	110
131	Raman scattering quantitative analysis of the anion chemical composition in kesterite Cu ₂ ZnSn(S _x Se _{1-x}) ₄ solid solutions. Journal of Alloys and Compounds, 2015, 628, 464-470.	2.8	69
132	Influence of compositionally induced defects on the vibrational properties of device grade Cu ₂ ZnSnSe ₄ absorbers for kesterite based solar cells. Applied Physics Letters, 2015, 106, .	1.5	135
133	Non-destructive assessment of ZnO:Al window layers in advanced Cu(In,Ga)Se ₂ photovoltaic technologies. Physica Status Solidi (A) Applications and Materials Science, 2015, 212, 56-60.	0.8	12
134	Advanced characterization of electrodeposition-based high efficiency solar cells: Non-destructive Raman scattering quantitative assessment of the anion chemical composition in Cu(In,Ga)(S,Se) ₂ absorbers. Solar Energy Materials and Solar Cells, 2015, 143, 212-217.	3.0	26
135	Complex Surface Chemistry of Kesterites: Cu/Zn Reordering after Low Temperature Postdeposition Annealing and Its Role in High Performance Devices. Chemistry of Materials, 2015, 27, 5279-5287.	3.2	99
136	Synthesis of CuIn(S,Se) ₂ quaternary alloys by screen printing and selenization-sulfurization sequential steps: Development of composition graded absorbers for low cost photovoltaic devices. Materials Chemistry and Physics, 2015, 160, 237-243.	2.0	9
137	Formation and impact of secondary phases in Cu-poor Zn-rich Cu ₂ ZnSn(S _{1-x} Se _x) ₄ based solar cells. Solar Energy Materials and Solar Cells, 2015, 140, 289-298.	3.0	60
138	Compositional paradigms in multinary compound systems for photovoltaic applications: a case study of kesterites. Journal of Materials Chemistry A, 2015, 3, 9451-9455.	5.2	34
139	Zn-poor Cu ₂ ZnSnSe ₄ thin films and solar cell devices. Physica Status Solidi (A) Applications and Materials Science, 2015, 212, 109-115.	0.8	13
140	Cu ₂ ZnSnSe ₄ absorber layers deposited by spray pyrolysis for advanced photovoltaic technology. Physica Status Solidi (A) Applications and Materials Science, 2015, 212, 126-134.	0.8	7
141	Electrical properties of sprayed Cu ₂ ZnSnSe ₄ thin films and its relation with secondary phase formation and solar cell performance. Solar Energy Materials and Solar Cells, 2015, 132, 557-562.	3.0	61
142	CuIn _{1-x} Al _x Se ₂ thin film solar cells with depth gradient composition prepared by selenization of evaporated metallic precursors. Solar Energy Materials and Solar Cells, 2015, 132, 245-251.	3.0	22
143	Route towards low cost-high efficiency second generation solar cells: current status and perspectives. Journal of Materials Science: Materials in Electronics, 2015, 26, 5562-5573.	1.1	38
144	Fabrication and characterization of kesterite Cu ₂ ZnSnSe ₄ thin films deposited by electrostatic spray assisted vapour deposition method. Physica Status Solidi (A) Applications and Materials Science, 2015, 212, 135-139.	0.8	10

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145	Characterization of Cu ₂ ZnSnSe ₄ solar cells prepared from electrochemically co-deposited Cu-Zn-Sn alloy. Solar Energy Materials and Solar Cells, 2015, 132, 21-28.	3.0	28
146	Raman scattering analysis of electrodeposited Cu(In,Ga)Se ₂ solar cells: Impact of ordered vacancy compounds on cell efficiency. Applied Physics Letters, 2014, 105, .	1.5	49
147	Multiwavelength excitation Raman scattering of Cu ₂ ZnSn(S _x Se _{1-x}) ₄ (0 ≤ x ≤ 1) polycrystalline thin films: Vibrational properties of sulfoselenide solid solutions. Applied Physics Letters, 2014, 105, .	1.5	64
148	Rapid thermal processing of Cu ₂ ZnSnSe ₄ thin films. , 2014, , .		1
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150	Secondary phase formation in Zn-rich Cu ₂ ZnSnSe ₄ -based solar cells annealed in low pressure and temperature conditions. Progress in Photovoltaics: Research and Applications, 2014, 22, 479-487.	4.4	97
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